

A category of extremely-fast events (EFEs) in pPCGe detectors used in CDEX

LiTao Yang

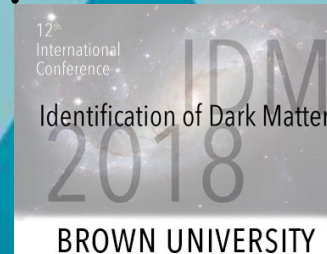
CDEX Collaboration

Tsinghua University

July. 26, 2018



中国锦屏地下实验室
China Jinping Underground Laboratory



BROWN UNIVERSITY

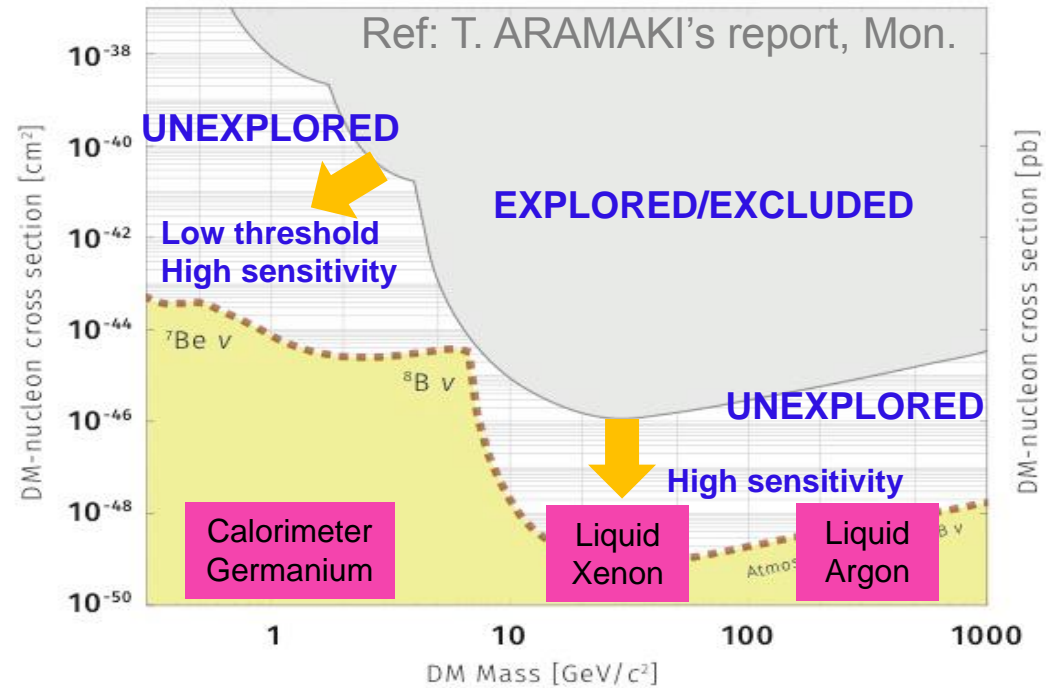
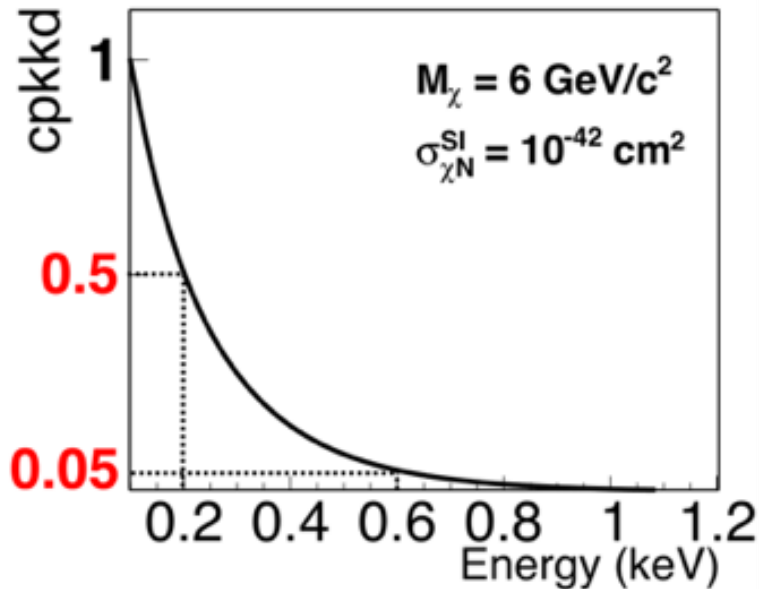
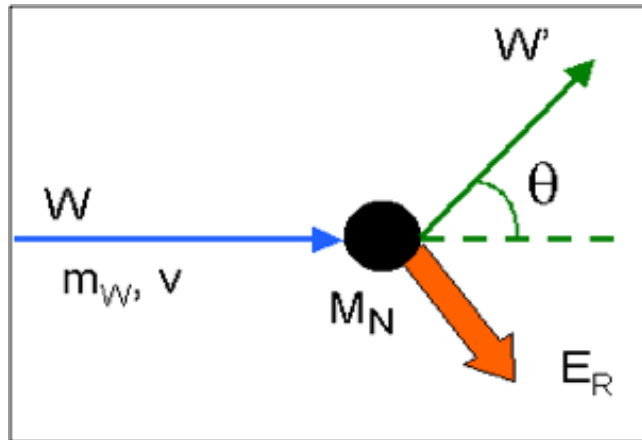
23 - 27 JULY 2018

Identification of Dark Matter 2018@Brown University, July 23-27 2018

Outline

- ❖ 1. pPCGe in CDEX
- ❖ 2. Extremely-fast events (EFEs) in pPCGe
- ❖ 3. What we learned from EFEs studies?
- ❖ 4. Summary

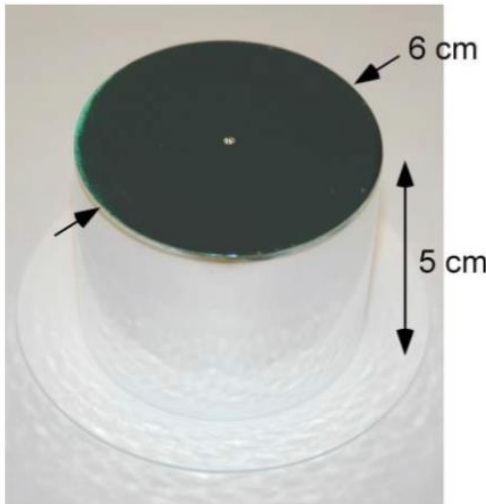
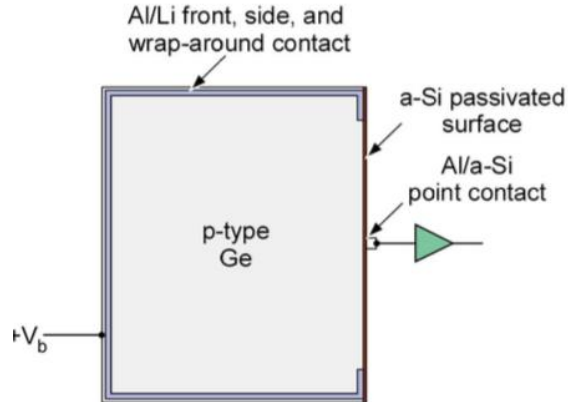
Direct detection of WIMP



Requirements for DM search:

- ✓ Low background
- ✓ Low threshold
- ✓ Particle discrimination
- ✓ Long-time stability

Point Contact Germanium (PCGe) detector



$$C_{PPC} = 2\pi\epsilon r$$

~1 pF possible

- **Good candidate for light DM**
 - ✓ Low threshold: ~ 200 eV
 - ✓ Excellent energy resolution: FWHM ~200 eV @ 10.37 keV, 4.3 keV @ 2039 keV (CDEX1A)
 - ✓ Long-time stability

➤ Challenges

- ✓ Control the material background near PCGe
- ✓ Decrease the cosmogenic background
- ✓ No particle discrimination
- ✓ Large mass

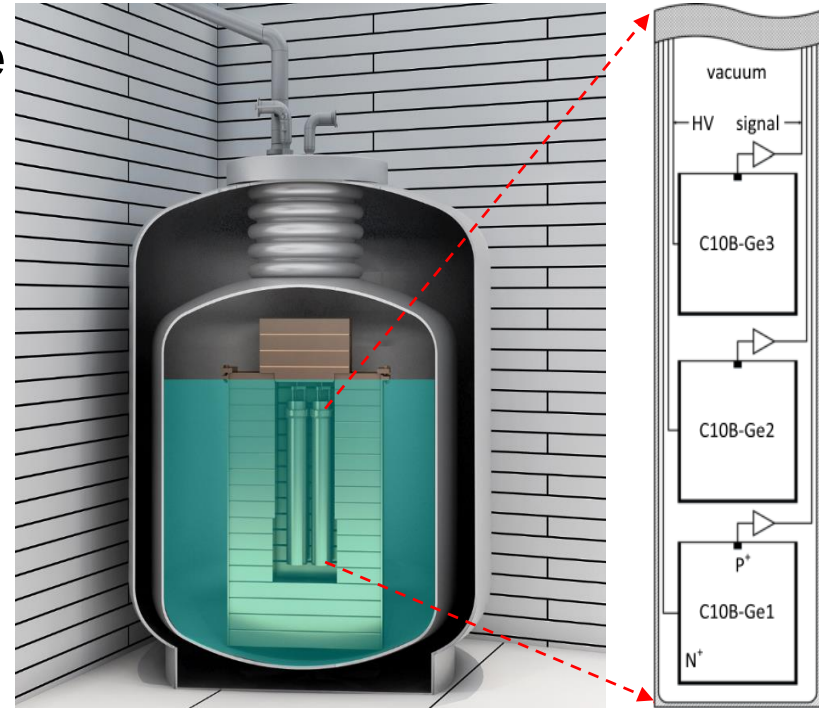
❖ Light WIMP searches with pPCGe

❖ CDEX-10 detectors:

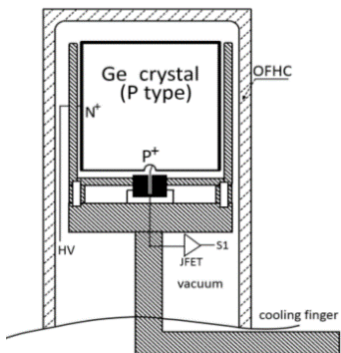
- ✓ three triple-element pPCGe strings
- ✓ total mass of about 10kg
- ✓ immersed in liquid nitrogen

Based on the CDEX-1B prototype:

- ✓ 1kg-scale pPCGe
- ✓ Large-mass “prototype” (1008 g)
- ✓ Low energy threshold (< 160 eVee)



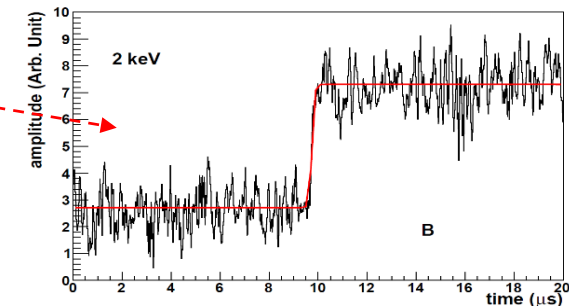
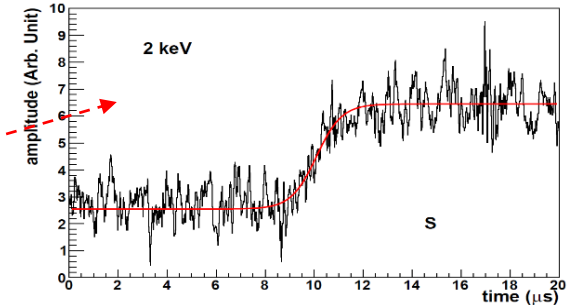
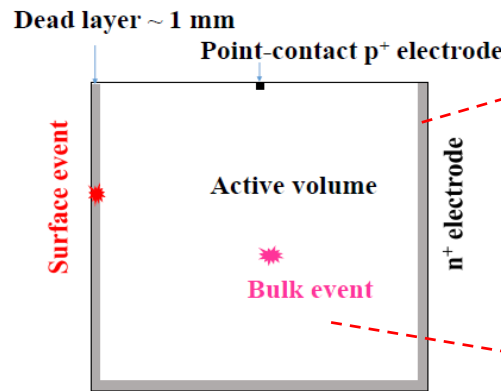
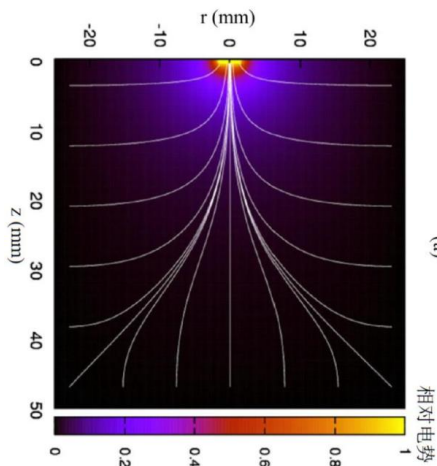
LN2 tank: 1.5 m(D)*1.9m(H)



Bulk and Surface events in pPCGe

Dead layer:

- ✓ Lithium diffusion technology of surface N+ electrode;
- ✓ the electric field is weak, and the electron-hole pair drifts slowly;
- ✓ Surface event: Amplitude (Energy) loss, long rise time;
- ✓ “Self-shielding effect”: external low γ /X rays will be shielded by this layer;



The surface signals should be removed:

❖ Active volume correction

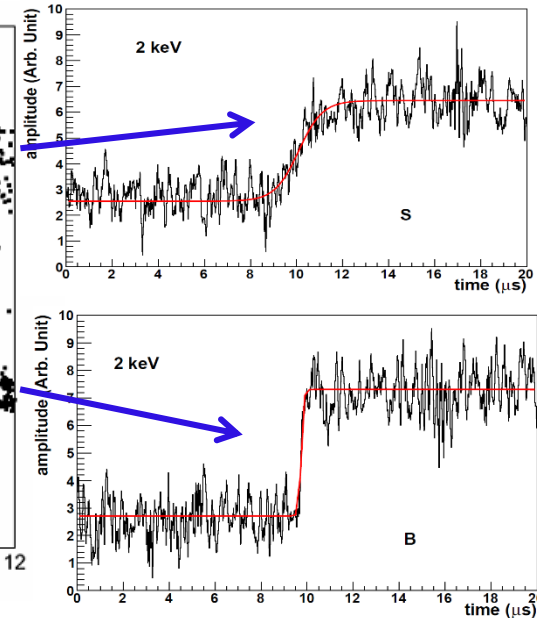
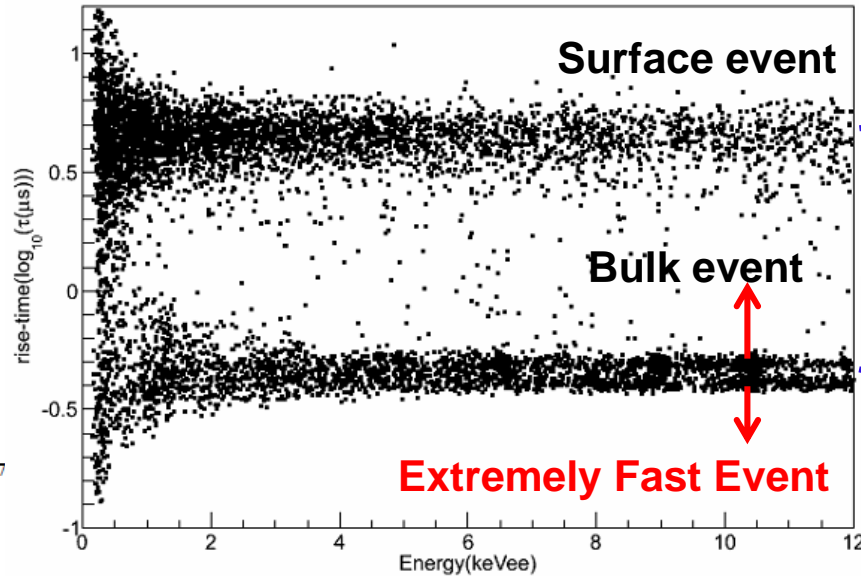
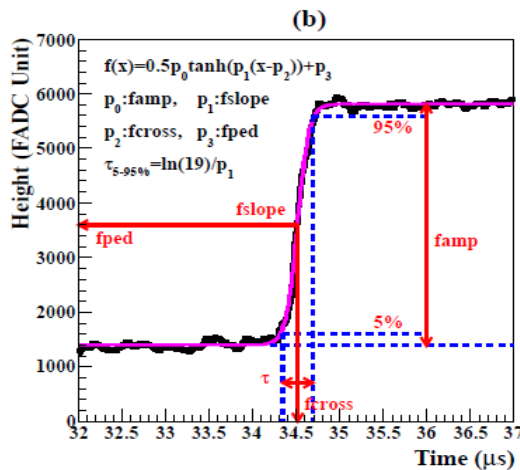
→ dead layer thickness measurement: 0.88 ± 0.12 mm (CDEX-1B)--939g

❖ B/S identification efficiency correction use rise time difference

B/S discrimination

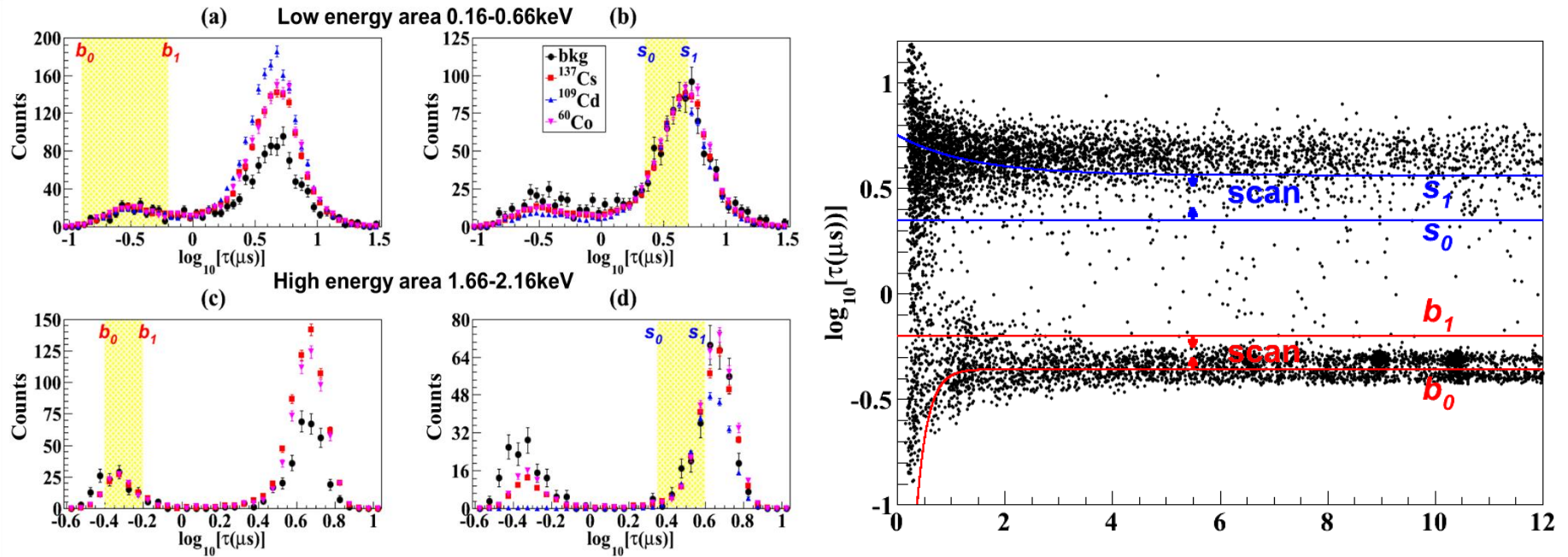
CDEX-10 background data:

- ❖ **Surface event:** longer rise time, false energy value;
- ❖ **Bulk event:** events happened in the active bulk volume;
- ❖ **Extremely-fast event:** faster rise time than Bulk events, happened at the strong electric field area near the point electrode; (has been confirmed by source experiments and the detector electric simulation)



B/S discrimination

Assumption: At low energies, different sources and background share the same rise-time PDFs $f_B(E, \tau)$ and $f_S(E, \tau)$ for bulk events and surface events.



Sources-independent bulk/surface rise-time distribution PDFs

$$N_i(E, \tau) = N_{Bi}(E, \tau) + N_{Si}(E, \tau) = \beta_i(E)f_B(E, \tau) + \xi_i(E)f_S(E, \tau).$$

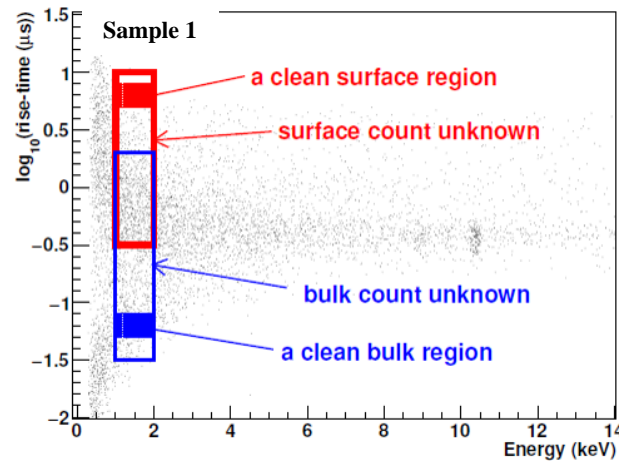
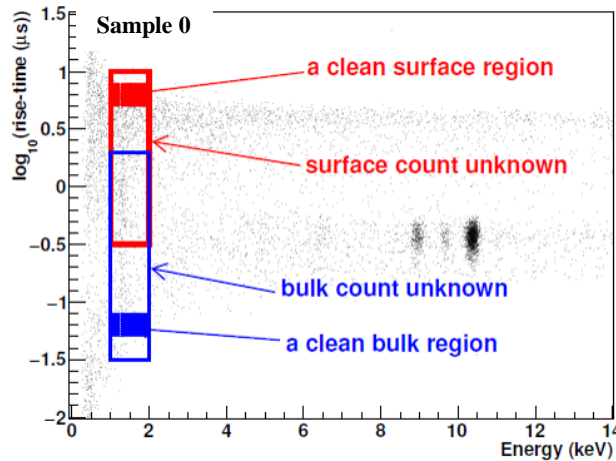
sources index τ -independent

Sources-independent bulk/surface rise-time distribution PDFs

$$N_i(E, \tau) = N_{Bi}(E, \tau) + N_{Si}(E, \tau) = \beta_i(E) f_B(E, \tau) + \xi_i(E) f_S(E, \tau).$$

sources index τ -independent

$$\beta_0(E) f_B(E, \tau) = \frac{N_1(E, \tau) - [\xi_1(E)/\xi_0(E)] N_0(E, \tau)}{[\beta_1(E)/\beta_0(E)] - [\xi_1(E)/\xi_0(E)]}.$$



$$\frac{\beta_i(E)}{\beta_j(E)} = \frac{\int_{b_0}^{b_1} \beta_i(E) f_B(E, \tau)}{\int_{b_0}^{b_1} \beta_j(E) f_B(E, \tau)} = \frac{\int_{b_0}^{b_1} N_i(E, \tau)}{\int_{b_0}^{b_1} N_j(E, \tau)}$$

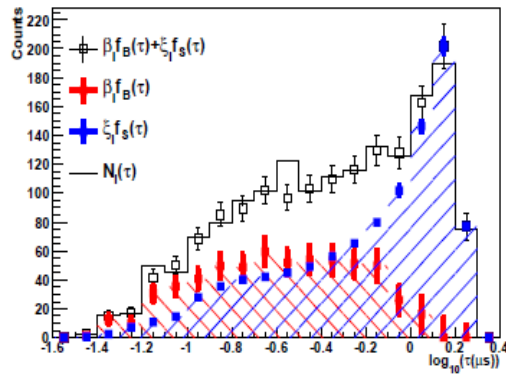
$$\frac{\xi_i(E)}{\xi_j(E)} = \frac{\int_{s_0}^{s_1} \xi_i(E) f_S(E, \tau)}{\int_{s_0}^{s_1} \xi_j(E) f_S(E, \tau)} = \frac{\int_{s_0}^{s_1} N_i(E, \tau)}{\int_{s_0}^{s_1} N_j(E, \tau)}$$

B/S disc. --Ratio Method

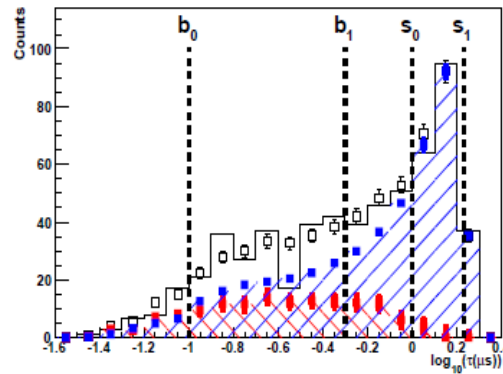
- For a collection of different sources with differing Bulk to Surface event ratios can be used to find N_{Bi} and N_{Si} by χ^2 minimization:

$$\chi^2(E, \tau) = \sum_i \frac{[\beta_i(E) f_B(E, \tau) + \xi_i(E) f_S(E, \tau) - N_i(E, \tau)]^2}{\Delta N_i(E, \tau)^2}$$

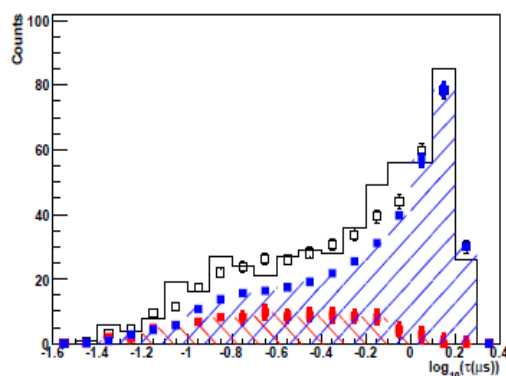
AC⁻, 0.25-0.35 keVee



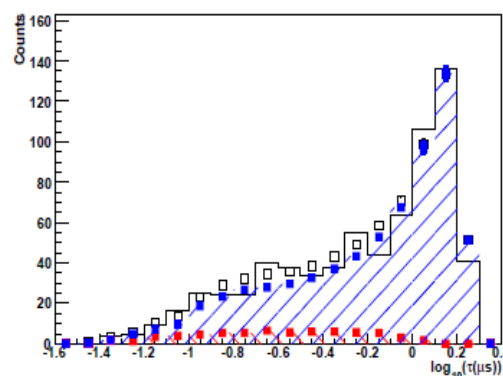
AC⁺



¹³⁷Cs



⁶⁰Co



- “pure” region: Cross-contamination regions

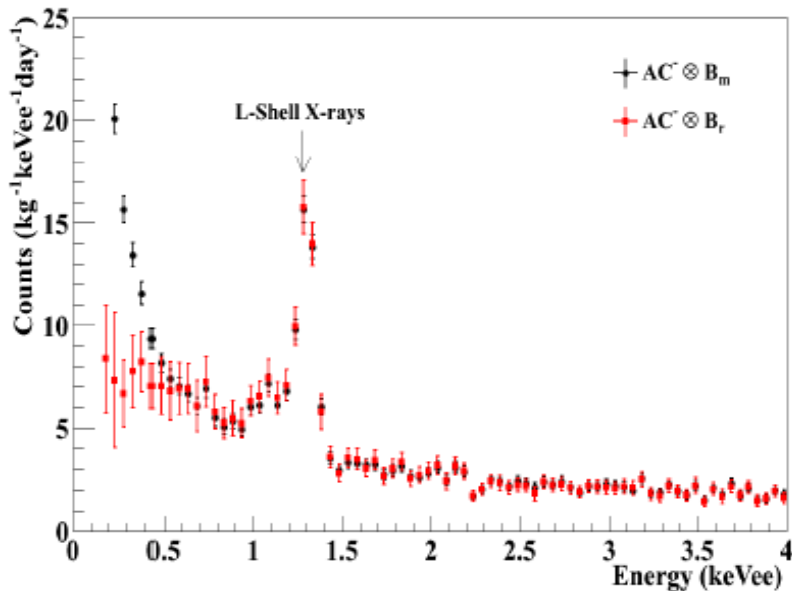
$$\beta_i^{(n)}(E) = \beta_i^0(E) - \int_{b_0}^{b_1} \xi_i^{(n-1)}(E) f_S^{(n-1)}(E, \tau) d\tau.$$

- Final $B_{ri}(E)$ equals the integral of $\beta_i f_B(E, \tau)$:

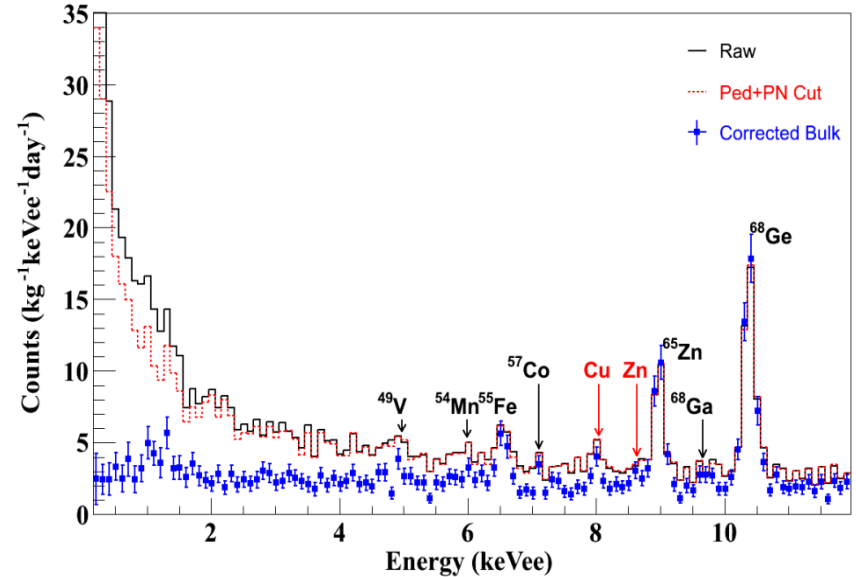
$$\begin{aligned} B_{ri}(E) &= \int_{\text{all } \tau} N_{Bi}(E, \tau) d\tau \\ &= \int_{\text{all } \tau} \beta_i^{(n)}(E) f_B^{(n)}(E, \tau) d\tau. \end{aligned}$$

Ratio Method in CDEX-1 and CDEX-10

- ✓ Analysis threshold: 160 eVee
- ✓ Count rate @160 eVee:
 - ✓ Before BS discrimination: >30 cpkkd
 - ✓ After: ~8 cpkkd (CDEX-1B) and ~2.5 cpkkd (CDEX-10)

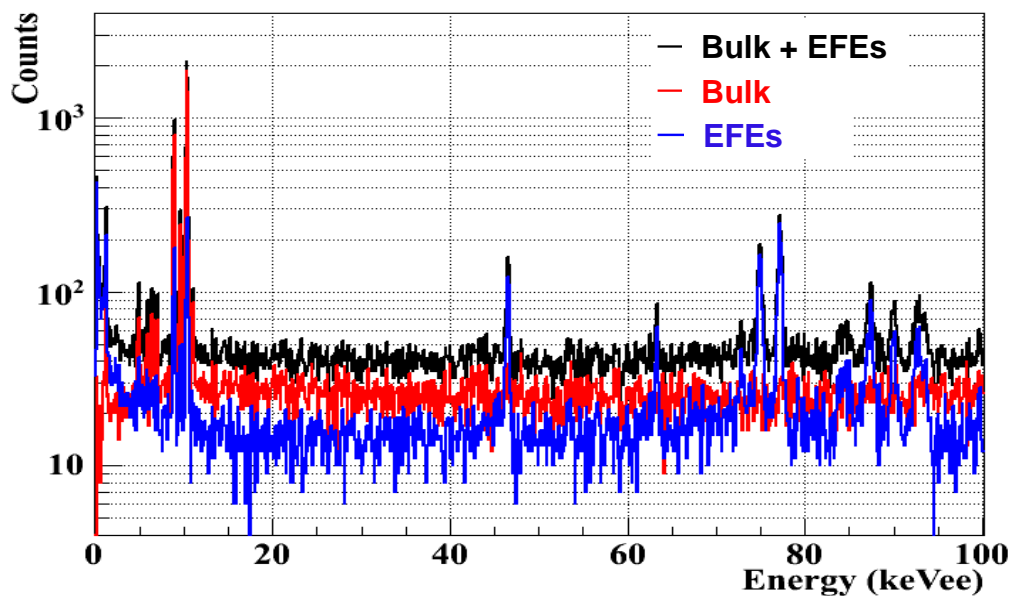
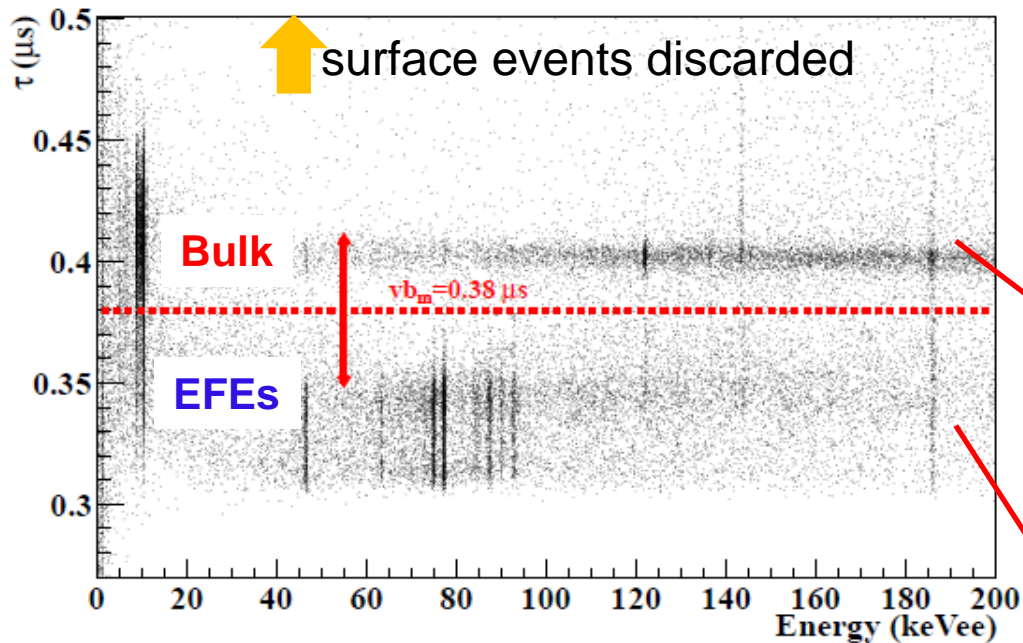


CDEX-1B



CDEX-10

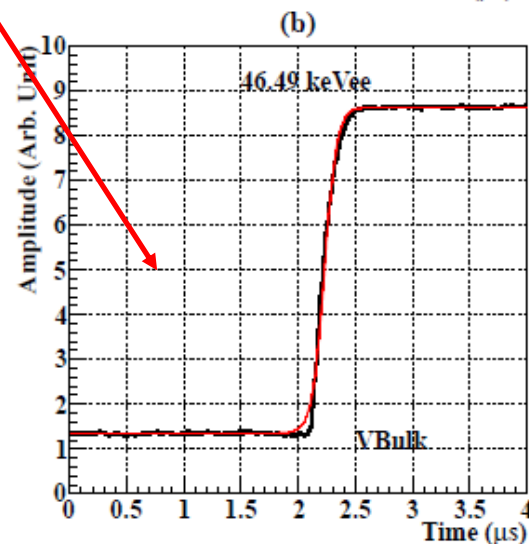
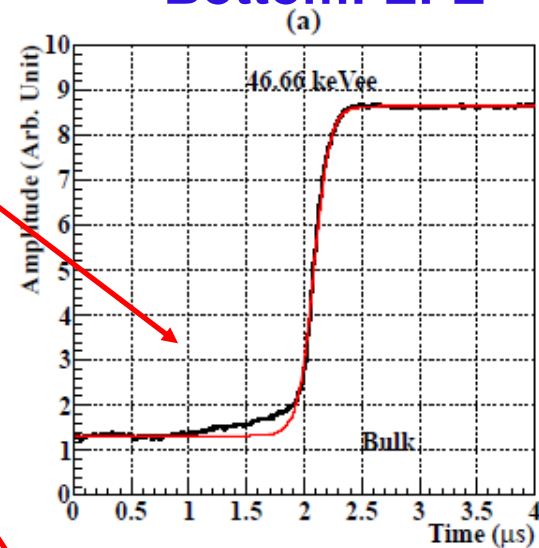
EFEs in CDEX-1B background data



❖ Measured pulses:

✓ Top: Bulk event

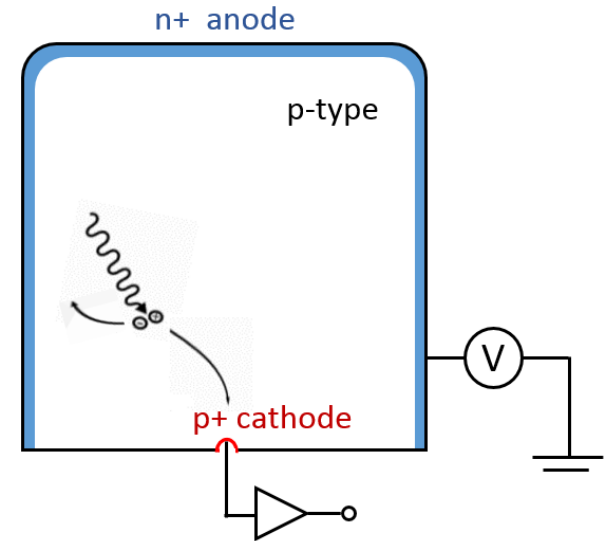
✓ Bottom: EFE



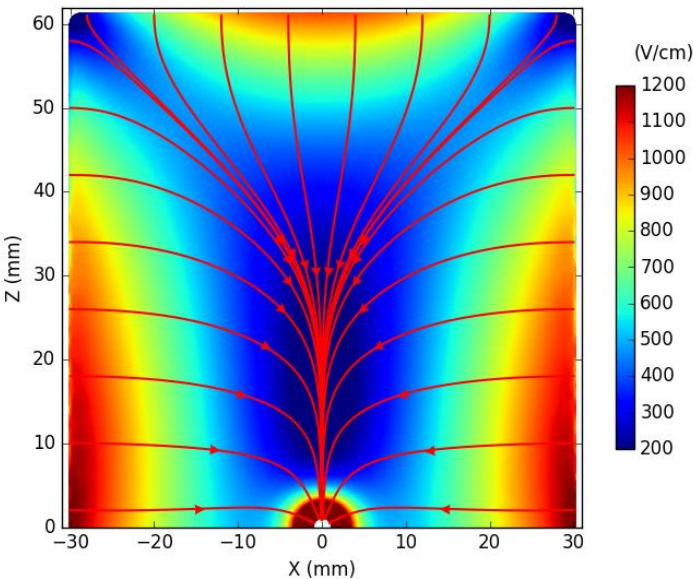
EFEs origin -- qualitative simulation

P-type Point-Contact (PPC) detector:

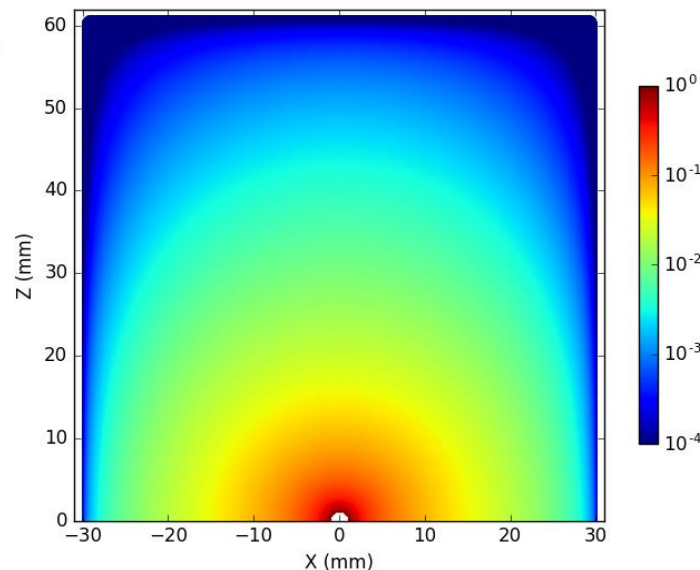
- Small point-like central contact
- Especially low capacitance ($\sim 1\text{pF}$) gives superb energy resolution and low energy threshold



Electric field



Weighting potential



Impurity concentration:

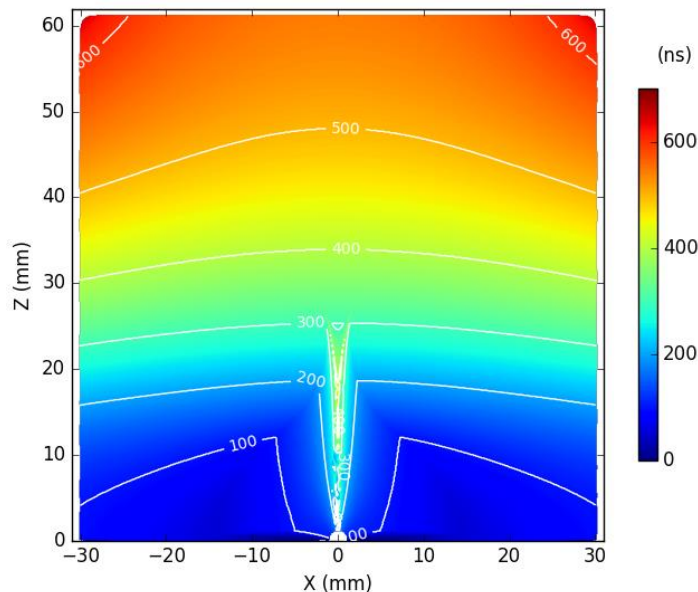
- $[-0.5, -0.8] \times 10^{10}\text{cm}^{-3}$
- no radial gradient

Bias Voltage:

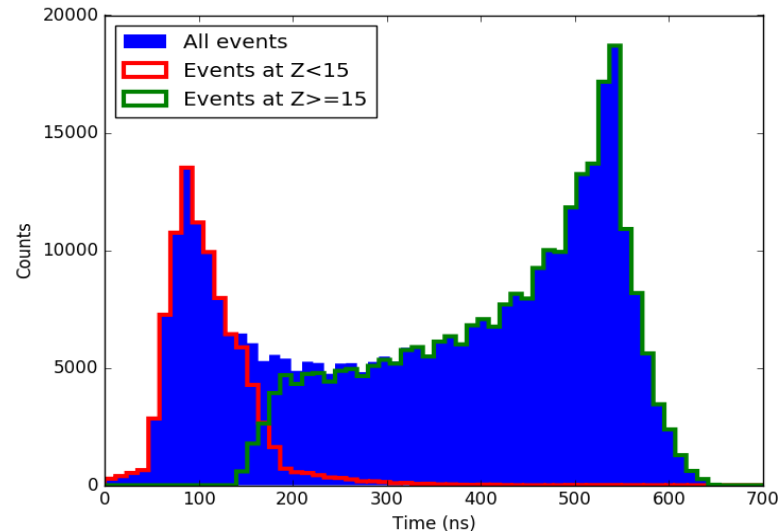
- + 3000V

EFEs origin -- qualitative simulation

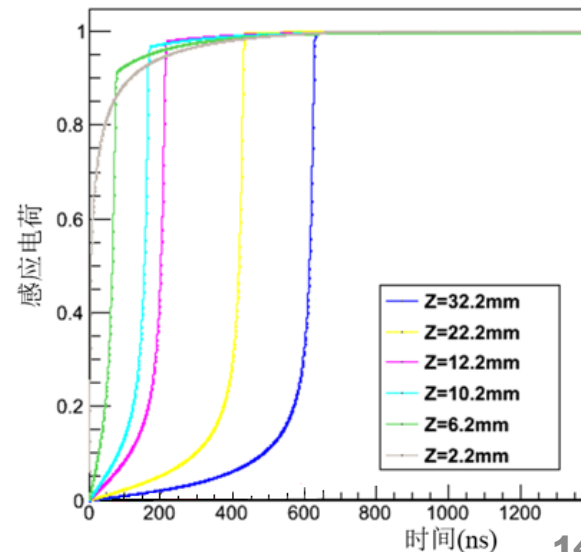
Drift time contour



Drift time distribution

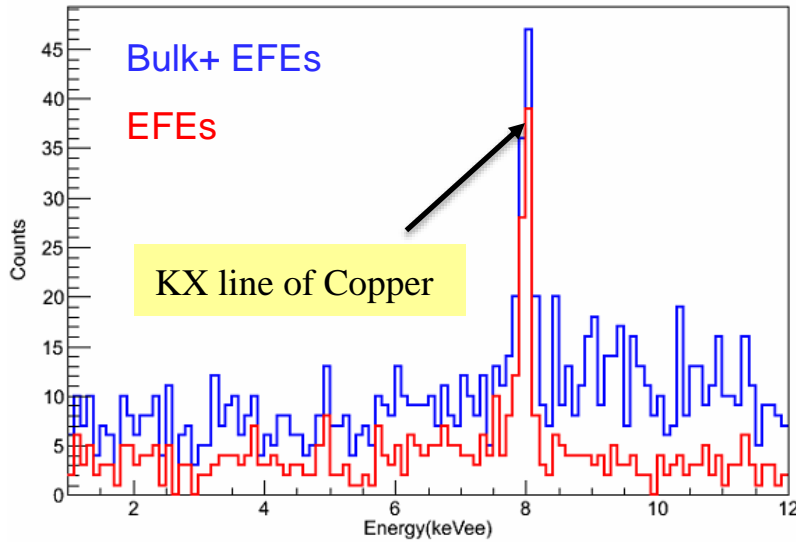


- The very-bulk events mainly arise from the bottom part of the PPC detector
- Very-bulk events discrimination can probably be used for background rejection

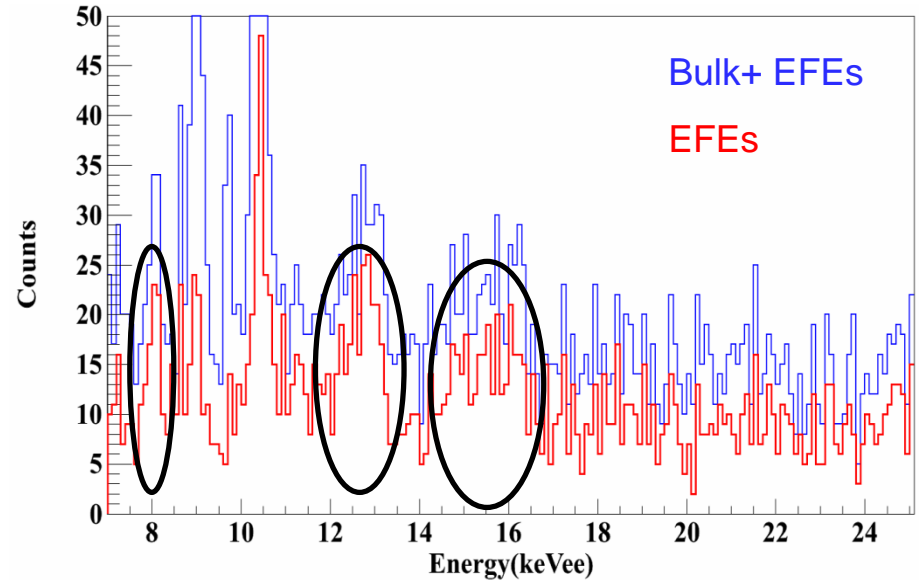


EFEs origin -- Experimental verification

^{109}Cd gamma source



Background spectrum



- ❖ 8 keV X-rays from Copper was observed in EFes spectrum of the ^{109}Cd samples;
- ❖ In the background spectrum, there are some clear peaks (12-16keV), which are dominated as EFes;
- ❖ Experimentally verified that the ultra-fast case comes from the end face of the point electrode where there is no dead layer.

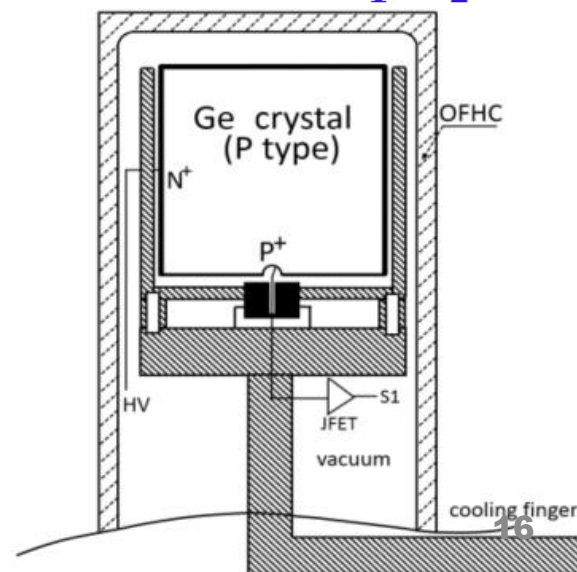
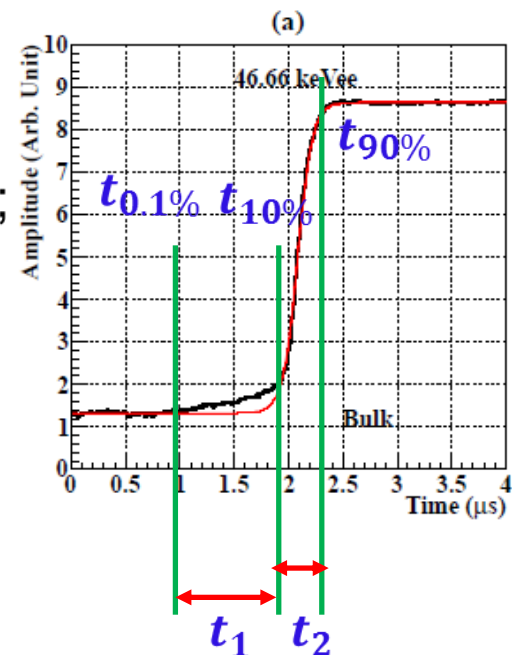
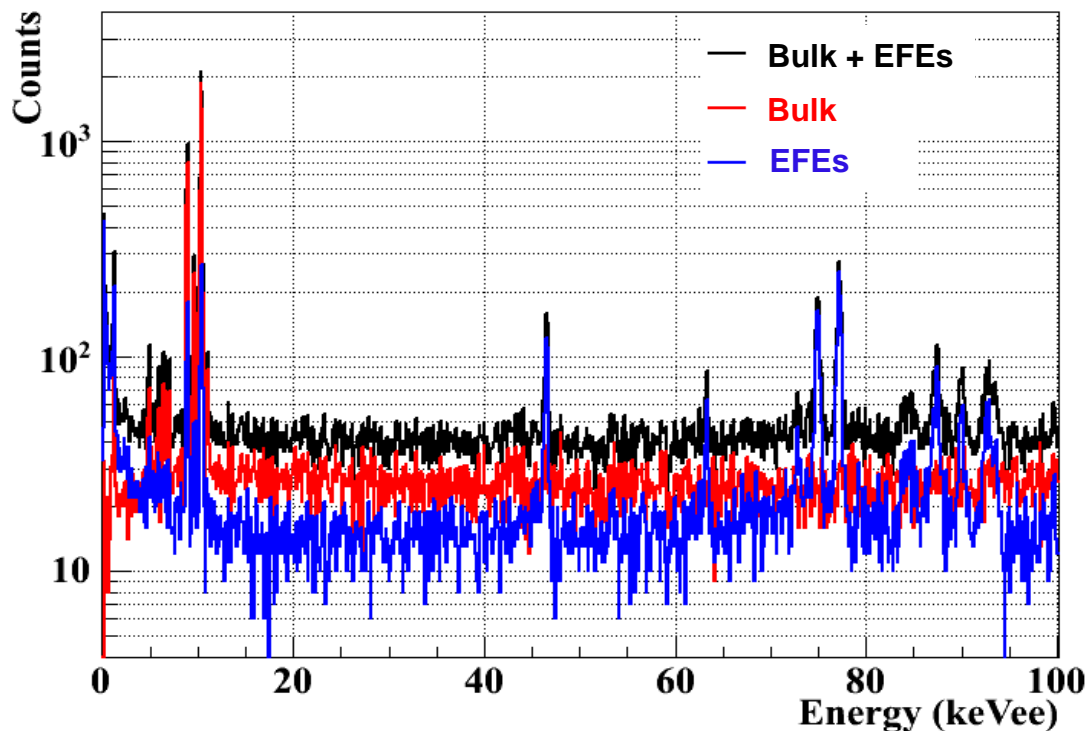
Nuclide	Type	Energy(keV)
Cu	L α	8.04
Pb	L β	12.62
Bi	L β	13.01
Th	L α	12.85
	L β	15.62 16.20
Ra	L α	12.34 12.20
		L β

What we learned from EFEs studies? (1)

(1) Suppress the background level

define the drift time: $t_1 = t_{10\%} - t_{0.1\%}$

- Drift time is related to the energy deposition location;
- Possibility of fiducial volume selection, remove as much bkg as possible while retaining as much fiducial mass as possible.

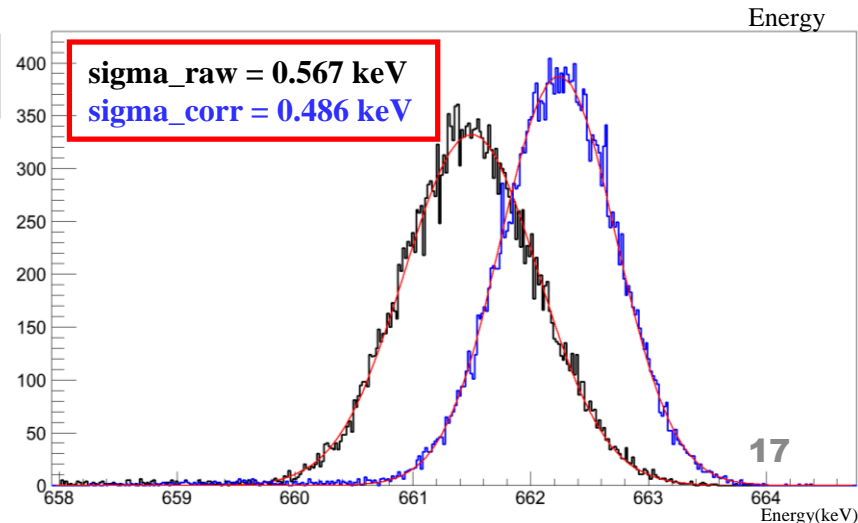
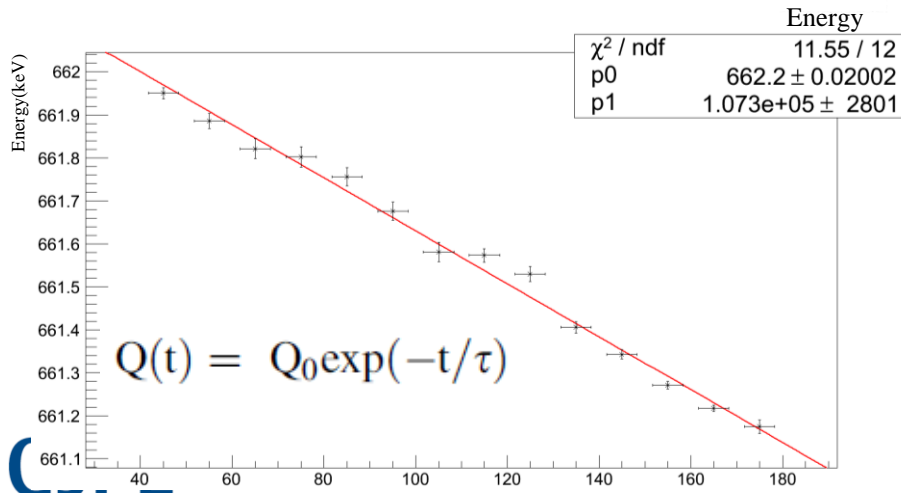
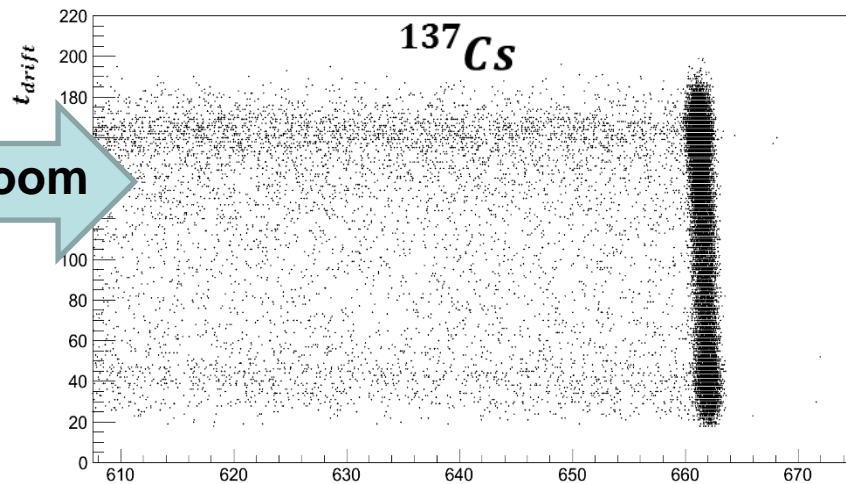
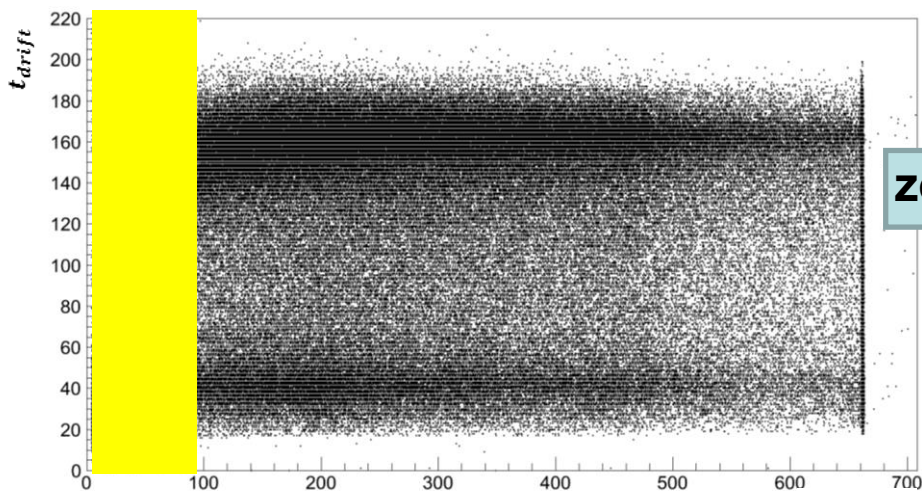


What we learned from EFEs studies? (2)

(2) Improve energy resolution

$$Q_{trapping} = Q_0 \cdot \left[1 - \exp\left(-\frac{t_{drift}}{\tau}\right) \right]$$

- Distribution of $t_{drift} - E$ provides information on τ of the carriers;
- Correct the energy to improve the energy resolution;

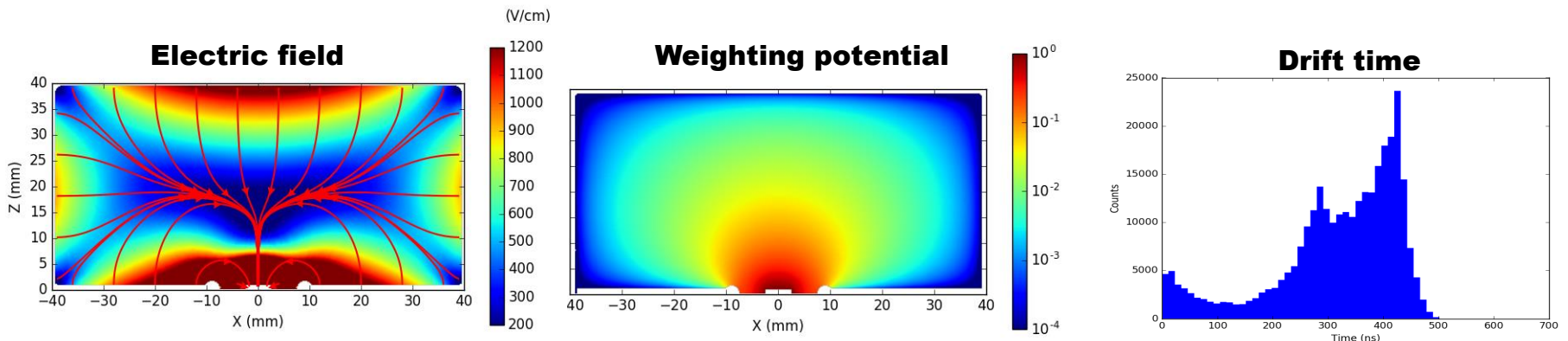
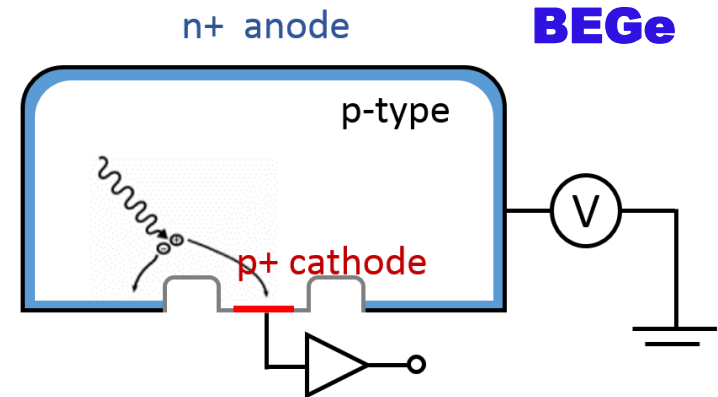


What we learned from EFEs studies? (3)

- ❖ n+ anode covers the front, lateral and most of the bottom part, which helps to shield the background events;
- ❖ Optimization of the ratio of diameter to height, short drift time length and uniform distribution results in better energy resolution.

BEGe detectors with thick window:

- ✓ a planar p-type detector with a relatively small cathode on the bottom side
- ✓ relatively small capacitance (a few pF)
- ✓ smaller EFEs region near the p+ contact



Summary

- ✓ pPCGe has many advantages and has been used in CDEX for DM direct detection;
- ✓ The B/S discrimination in pPCGe can significantly reduce the background level;
- ✓ The study of Extremely Fast Events (EFEs) can help to better understand the background origins;
- ✓ The analysis of the drift time helps to improve the energy resolution at high energy ranges;
- ✓ This provides ideas for the structural design of detectors in future.



Thanks for your attention!

B/S discrimination issues

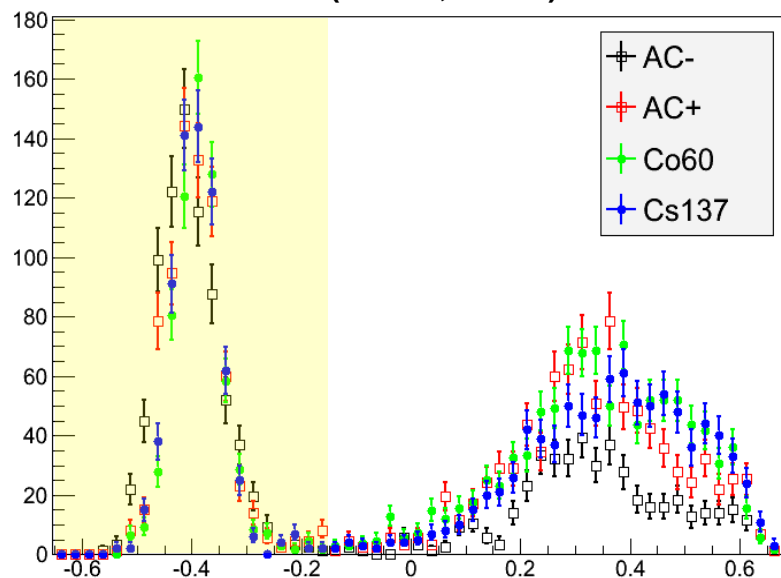
CDEX-1B data

- The validity of this analysis requires calibration source data with consistent rise-time distributions.

High energies:

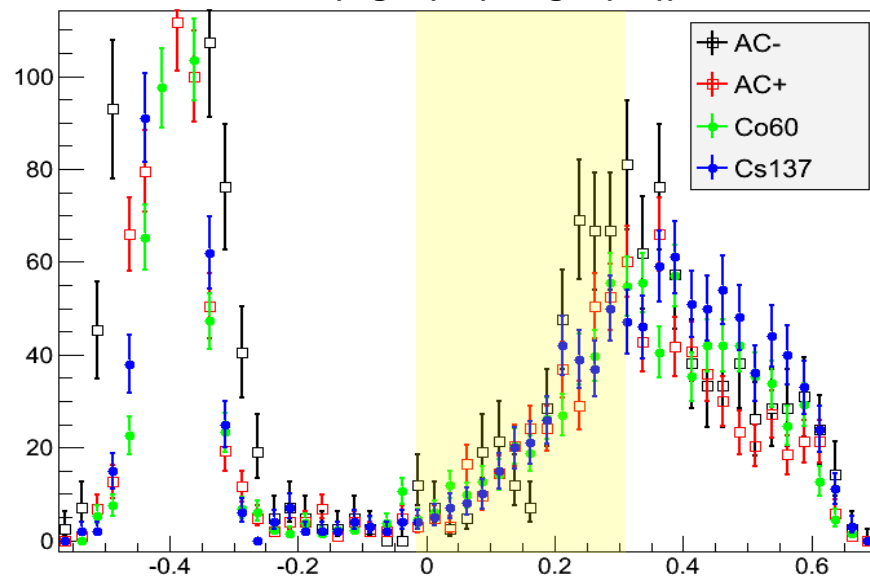
5.0-5.5 keV

Nor(-0.425 , -0.225)



5.0-5.5 keV

Nor(log10(0.9) , log10(1.6))



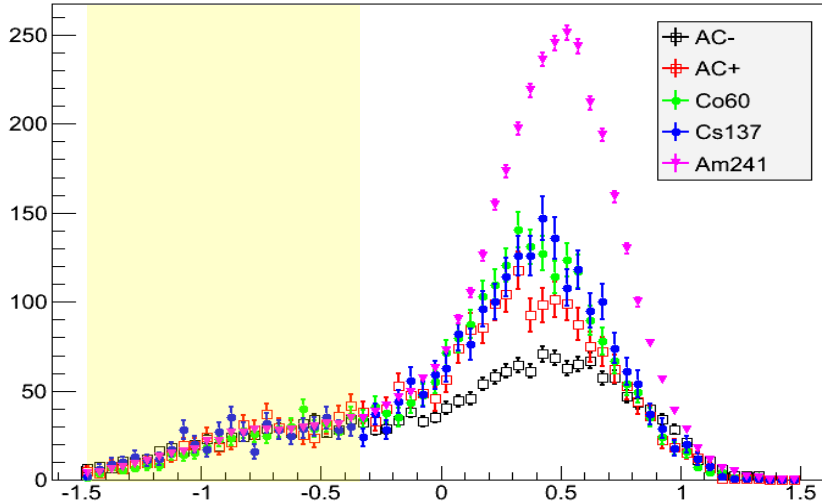
B/S discrimination issues

CDEX-1B data

Low Energies:

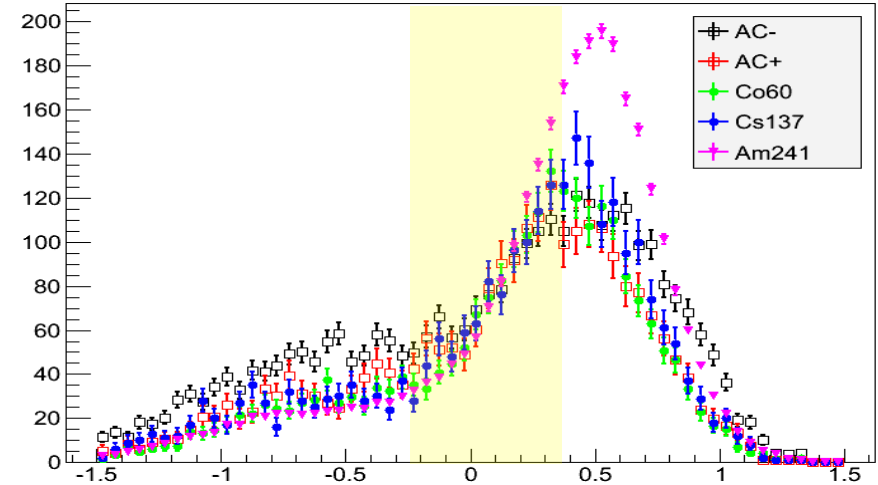
0.2-0.4 keV

Nor(-1.0, -0.5)



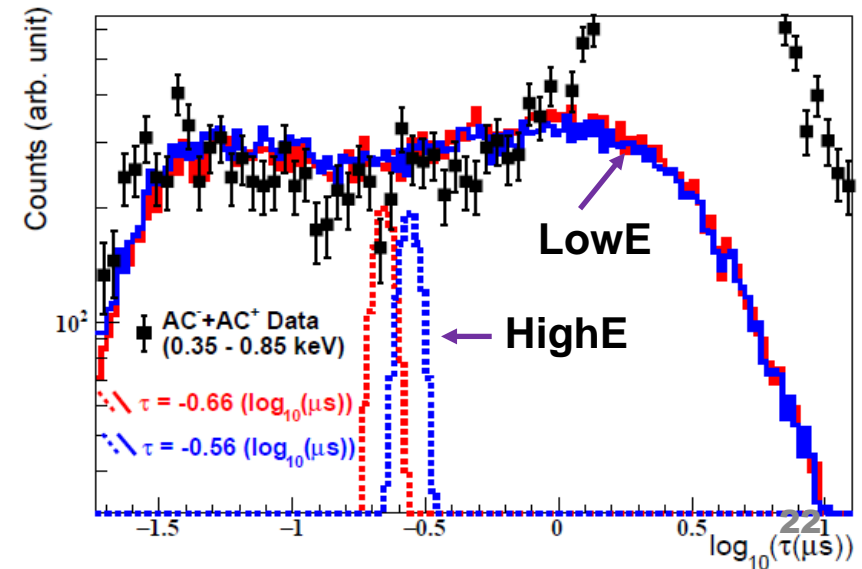
0.2-0.4 keV

Nor(log10(0.9), log10(1.6))



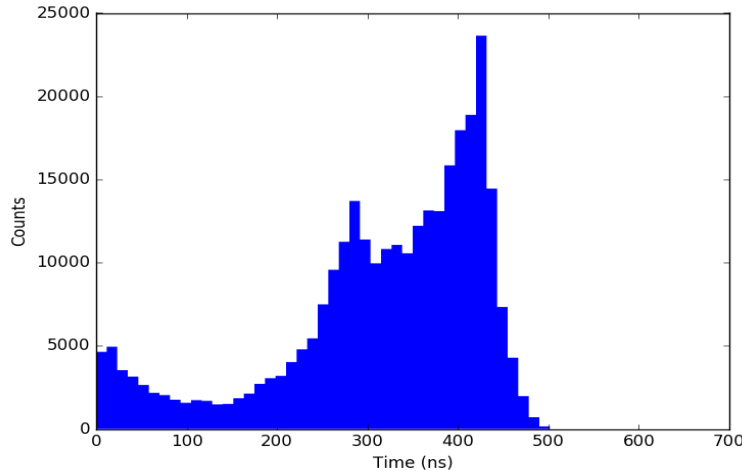
Rise-time is related to the electric field distribution and the noise level:

- ❖ High energies: electric field dominated
- ❖ Low energies: noise smearing out effects dominated

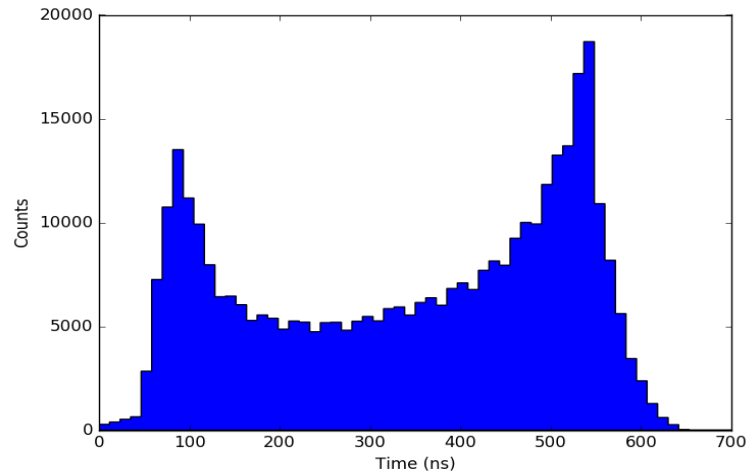


Pulse shape response

Drift time distribution of BEGe



Drift time distribution of PPCGe



$$Q_{trapping} = Q_0 \cdot \left[1 - \exp\left(-\frac{t_{drift}}{\tau}\right) \right]$$

- Short drift time length and uniform distribution results in better energy resolution